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P.E.S. College of Engineering, Mandya - 571 401 (An Autonomous Institution affiliated to VTU, Belgaum) Sixth Semester, B.E Electrical and Electronics Engineering Semester End Examination; June/July – 2015 Microcontrollers Time: 3 hrs						
Ne	ote: Answer any FIVE full question	ns, selecting at least TWO full que	estions from	each part.		
		PART - A				
1. a.	With block diagram briefly expla	ain Harvard and Von Neumann CP	'U architect	ures.		
b.	With respect to 8051 microcontro	oller briefly explain the following	:			
	(i) Flags and program status wor	d (ii) Internal memory	(iii) Stac	k operation.		
c.	Write a note on I/O ports of 805	l microcontrollers.				
2 a.	With examples, explain different	addressing modes of 8051 microc	controller.			
b.	Explain the following 8051 instr	uctions with examples:				
	(i) MOV C (ii) RRC (iii)	CPLA (iv) ADD C (v) DIV				
3 a.	Write the O\P and flag status after	r the following program is execute	d			
	MOV A, # +96 ;					
	MOV R ₁ , # +70;					
	ADD A, R \perp					
b.	Find the content of registers A &	B after the following code in each	1 case :			
	(i) MOV A, # 37H (ii) MOV A, #37H				
	ANL A, # OCA H	ORL A, # OCA H				
	(iii) MOV A, # 85H (iv	w) MOV A, #95H;				
	CPL A	MOV B, # 05H;				
	ADD A, #⊥	MUL AB.				
c.	Take 10 bytes of data from RAM	M locations 45 H to 54 H, add 0	2 to each of	f them and save		
	the result in data RAM locations 79 H down to 70 H.					
4 a.	With an example explain the foll					
	(i) INC and DEC	(ii) SETB c and SETB b				
	(iii) ANL c, b and ANL c, /b	(iv) CLR c and CLR b				
b.	ADD the BCD numbers found in internal RAM 25 h, 26 h and 27 h. Put the result in RAM					
	locations 31 h (MSB) and 30 h (LSB).					

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c.	Write a program to multiply the unsigned number in register R_3 by the unsigned number on	6					
	Port 2 and Put the result in external RAM locations 10 h (MSB) and 11 h (LSB)						
	PART – B						
5 a.	Briefly explain the following jump instructions with examples :						
	(i) JNB b, radd (ii) JBC b, radd (iii) LJMP radd.	6					
b.	The number A6 h is placed somewhere in external RAM between locations 0100 h and						
	0200 h. Find the address of that location and put the address in R6 (LSB) and R7(MSB)						
c.	Assume internal RAM memory locations $40 \text{ H} - 44 \text{ H}$ contain the daily temperature for five						
	days, as shown below. Search to see if any of the values equals 65. If value 65 does exist in						
	the table, Give its location to R4; otherwise make $R4 = 0$.						
	40 H = (76), 41 H = (79), 42 H = (69), 43 H = (65) 44 H = (62)						
6 a.	With reference to 8051 microcontroller briefly explain the functions of						
	(i) Timer 0 and Timer 1 registers (ii) TMOD registers (iii) TCON register						
b.	Write a program to generate a square wave of 50% duty cycle on P 1.5 bit. Use Timer 0 in						
	mode 1 Load the count as FFF2 H						
c.	Assume that $X_{TAL} = 11.0592$ MHz. What value is to be loaded into the timer's registers to						
	have a delay of 5 milli seconds?	6					
7 a.	Briefly explain the following with respect to serial communication :						
	(i) Half and full duplex transmission	8					
	(ii) Asynchronous and synchronous serial communication	0					
	(iii) RS 232 standards.						
b.	Briefly explain the role of TI flag bit and RI flag bit in serial communication.	6					
c.	Write a program to receive the data which has been sent in serial form and send it out to port						
	0 in parallel form. Also save the data at RAM location 60 H.	6					
8 a.	Mention the steps in executing an interrupt. List and explain the interrupts of 8051 micro						
1	controller.						
b.	How interrupts are enables and disables in 8051 microcontroller. Briefly explain.	6					
c.	Write a program to generate a square wave on port 0 which is half the frequency of the signal	ncy of the signal 6					
	applied at INTO Pin [Pin no. 3.2]						

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